

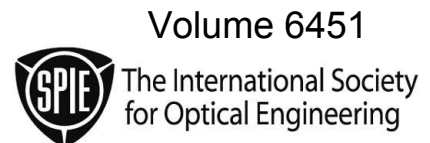
PROCEEDINGS OF SPIE

Solid State Lasers XVI: Technology and Devices

**Hanna J. Hoffman
Ramesh K. Shori
Norman Hodgson**
Editors

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Contents

ix Conference Committee

UV LASERS: CW

- 645102 **Continuous wave Praseodymium solid-state lasers (Invited Paper)** [6451-01]
G. Huber, A. Richter, E. Heumann, Univ. Hamburg (Germany)
- 645103 **UV generation by intracavity frequency doubling of an OPS-pumped Pr:YLF laser with 500 mW of cw power at 360 nm** [6451-02]
V. Ostroumov, W. Seelert, Coherent GmbH (Germany); L. Hunziker, C. Ihli, Coherent, Inc. (USA); A. Richter, E. Heumann, G. Huber, Univ. of Hamburg (Germany)
- 645104 **522/261 nm cw generation of Pr:YLF laser pumped by OPS laser** [6451-03]
V. Ostroumov, W. Seelert, Coherent GmbH, Luebeck (Germany); L. Hunziker, C. Ihli, Coherent Inc. (USA)
- 645105 **Stable CW low noise operation of a diode-pumped monolithic laser at 355 nm beyond 30 mW** [6451-04]
N. Aubert, T. Georges, C. Chauzat, R. Le Bras, Oxixus SA (France); P. Féron, École Nationale Supérieure des Sciences Appliquées et de Technologie (France)

UV LASERS: PULSED

- 645106 **Ultrafast frequency conversion sources for the visible and ultraviolet based on BiB₃O₆ (Invited Paper)** [6451-05]
M. Ebrahim-Zadeh, ICFO-The Institute of Photonics Sciences (Spain) and Institutio Catalana de Recerca i Estudis Avancats (Spain)

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The CID number appears on each page of the manuscript. The complete citation is used on the first page, and an abbreviated version on subsequent pages.

- 645107 **Frequency-tripled and quadrupled air-cooled modelocked Nd:YVO₄ laser with greater 6W average power** [6451-06]
A. Diening, O. Mehl, Coherent, Inc. (USA); S. Ahler, S. Butterworth, W. Seelert, Coherent GmbH, Lübeck (Germany)

OPTICALLY PUMPED SEMICONDUCTORS (OPS) AND DISK LASERS

- 645109 **Recent advances in optically pumped semiconductor lasers (Invited Paper)** [6451-08]
J. Chilla, Q.-Z. Shu, H. Zhou, E. Weiss, M. Reed, L. Spinelli, Coherent Inc. (USA)
- 64510A **Power-scaling of optically pumped semiconductor lasers** [6451-09]
L. E. Hunziker, Q.-Z. Shu, D. Bauer, C. Ihli, G. J. Mahnke, M. Rebut, J. R. Chilla, A. L. Caprara, H. Zhou, E. S. Weiss, M. K. Reed, Coherent, Inc. (USA)
- 64510B **Advances in power scalable, tunable, and mode-locked semiconductor disk lasers (Invited Paper)** [6451-72]
O. G. Okhotnikov, A. Härkönen, E. J. Saarinen, J. Rautiainen, R. Herda, M. Guina, Tampere Univ. of Technology (Finland)
- 64510C **New wavelengths in the yellow-orange range between 545 nm and 580 nm generated by an intracavity frequency-doubled optically pumped semiconductor laser** [6451-10]
S. Hilbich, W. Seelert, V. Ostroumov, C. Kannengiesser, R. v. Elm, J. Mueller, Coherent GmbH, Lübeck (Germany); E. Weiss, H. Zhou, J. Chilla, Coherent Inc. (USA)
- 64510D **Pulsed Yb:YAG thin disk laser with 100 W at 515 nm** [6451-11]
G. Hollemann, P. Heist, S. Heinitz, J. Symanowski, T. Eidam, JENOPTIK Laser, Optik, Systeme GmbH (Germany); C. Stolzenburg, A. Giesen, Univ. Stuttgart (Germany)
- 64510E **Thin disk Yb:YAG laser with Q-switching and frequency doubling for the generation of strong pulses at 515 nm with excellent beam properties** [6451-12]
C. Petermann, G. Hummelt, ELS Elektronik Laser System GmbH (Germany)

NEW DEVELOPMENTS IN DIODE PUMPED SOLID STATE LASERS

- 64510F **888-nm pumping of Nd:YVO₄ for high-power high-efficiency TEM₀₀ lasers (Invited Paper)** [6451-13]
L. McDonagh, Technische Univ. Kaiserslautern (Germany); R. Knappe, A. Nebel, Lumera Laser GmbH (Germany); R. Wallenstein, Technische Univ. Kaiserslautern (Germany)
- 64510G **High-power 885nm end-pumped Nd:YAG laser** [6451-14]
M. Frede, D. Freiburg, R. Wilhelm, D. Kracht, Laser Zentrum Hannover e.V. (Germany)
- 64510I **Diode pumped Nd:YGG laser for direct generation of pulsed 935-nm radiation for water vapour measurements** [6451-16]
J. Löhring, K. Nicklaus, N. Kujath, D. Hoffmann, Fraunhofer Institute for Laser Technology (Germany)
- 64510J **Nd:GSAG laser for water vapor detection by LIDAR near 942 nm** [6451-28]
F. Kallmeyer, M. Dziedzina, D. Schmidt, H.-J. Eichler, Technical Univ. of Berlin (Germany); R. Treichel, S. Nikolov, EADS Astrium GmbH (Germany)

MID IR LASERS

- 64510K **Mid-IR transition metal lasers (Invited Paper)** [6451-71]
K. L. Schepler, Air Force Research Lab. (USA)
- 64510L **Fe:ZnSe passive Q-switching of 2.8- μ m Er:Cr:YSGG laser cavity** [6451-20]
A. Gallian, A. Martinez, P. Marine, V. Fedorov, S. Mirov, Univ. of Alabama at Birmingham (USA); V. Badikov, Kuban State Univ. (Russia); D. Boutoussov, M. Andriasyan, BIOLASE Technology, Inc. (USA)
- 64510M **Cr:ZnSe laser crystal grown by Bridgeman technique: characteristics and laser performance** [6451-21]
P. Koranda, H. Jelínková, J. Šulc, M. Němec, Czech Technical Univ. in Prague (Czech Republic); M. E. Doroshenko, T. T. Basiev, General Physics Institute (Russia); V. K. Komar, A. S. Gerasimenko, V. M. Puzikov, Institute for Single Crystals (Ukraine)
- 64510N **Properties of Ho³⁺ -doped PbWO₄ as laser active and stimulated Raman scattering-active crystals promising for mid-IR applications** [6451-22]
I. S. Mirov, Vestavia Hills High School (USA) and Univ. of Alabama at Birmingham (USA); V. V. Fedorov, I. S. Moskalev, D. V. Martyshkin, Univ. of Alabama at Birmingham (USA); S. Yu. Beloglovski, S. F. Burachas, Y. A. Saveliev, A. M. Tseitline, North Crystals (USA)

LASERS IN THE EYE-SAFE RANGE

- 64510P **Volume Bragg grating improves characteristic of resonantly diode-pumped Er:YAG 1.65- μ m DPSSL** [6451-23]
I. Kudryashov, D. Garbuzov, Princeton Lightwave Inc. (USA); M. Dubinskii, Army Research Lab. (USA)
- 64510Q **Room temperature multi-wavelength operation in Er:YAlO₃** [6451-24]
S. Sharma, Univ. of California, Los Angeles (USA); C. L. Vergien, Air Force Research Labs. (USA); R. K. Shori, O. M. Stafsudd, Univ. of California, Los Angeles (USA)
- 64510R **Microchip Nd:YAG laser for safe laser applications** [6451-26]
H. Jelínková, J. Šulc, M. Němec, P. Koranda, Czech Technical Univ. in Prague (Czech Republic); J. Pašta, Central Military Hospital (Czech Republic); K. Nejezchleb, V. Škoda, Crytur, Ltd. (Czech Republic)

INJECTION SEEDED AND FREQUENCY STABLE LASERS

- 64510S **Multi ten-watt, ultra-stable, and tuneable Innoslab-based single frequency MOPA (Invited Paper)** [6451-17]
M. Höfer, M. Traub, R. Kleindienst, H. Sipma, H.-D. Hoffmann, Fraunhofer Institute for Laser Technology (Germany); P. Wessels, P. Burdack, InnoLight GmbH (Germany)
- 64510U **Single-frequency stabilization of frequency-tripled nanosecond Ti:sapphire laser injection-seeded for silicon atom optics (Invited Paper)** [6451-30]
Y. Shiomi, T. Yamamoto, H. Kumagai, A. Kobayashi, Osaka City Univ. (Japan)

CRYOGENICALLY COOLED LASERS

- 64510V **Cryogenically cooled Ti:sapphire amplifiers [6451-31]**
J.-M. Heritier, S. Fournier, G. J. Germann, B. Resan, R. Viselga, A. Fry, Coherent, Inc. (USA)
- 64510W **A high-average power femtosecond laser for synchrotron light source applications [6451-32]**
R. B. Wilcox, R. W. Schoenlein, Lawrence Berkeley National Lab. (USA)
- 64510X **High-power operation of cryogenic Yb:YAG (Invited Paper) [6451-33]**
K. F. Wall, B. Pati, P. Moulton, Q-Peak, Inc. (USA)
- 64510Y **Innovative high-power CW Yb:YAG cryogenic laser [6451-34]**
D. C. Brown, J. M. Singley, E. Yager, J. W. Kuper, B. J. Lotito, L. L. Bennett, Snake Creek Lasers, LLC (USA)

TUNABLE, MODE-LOCKED, AND ULTRAFEST LASERS

- 64510Z **Extended tunability of Ti:sapphire lasers in CW and quasi-CW operation [6451-35]**
I. MacGillivray, G. Friel, A. Bell, Coherent Scotland Ltd. (United Kingdom)
- 645110 **Pulse shaping, characterization, and phase compensation system for enhanced ultrafast laser performance [6451-36]**
B. Resan, A. Magana, S. Fournier, G. Germann, J.-M. Heritier, W. Tulloch, A. Fry, Coherent Inc. (USA)
- 645111 **Noncryogenic 10-kHz Ti:sapphire amplifier [6451-37]**
G. Matras, Lab. Hubert Curien, CNRS (France) and Thalès Laser SA (France); N. Huot, Lab. Hubert Curien, CNRS (France); E. Baubeau, Thalès Optronique SA (France); E. Audouard, Lab. Hubert Curien, CNRS (France)
- 645112 **Amplification of ultrashort pulses to 0.5 TW at 5 Hz with a flashlamp pumped Cr:LiSAF gain medium [6451-38]**
R. E. Samad, G. E. C. Nogueira, S. L. Baldochi, N. D. Vieira, Jr., IPEN, Comissão Nacional de Energia Nuclear (Brazil)
- 645113 **Semiconductor saturable absorbers with recovery time controlled through growth conditions [6451-75]**
M. D. Guina, Tampere Univ. of Technology (Finland) and RefleKron Ltd. (Finland); P. Tuomisto, O. G. Okhotnikov, Tampere Univ. of Technology (Finland); S. Marcinkevicius, Royal Institute of Technology (Sweden); K. Mizohata, J. Keinonen, Univ. of Helsinki (Finland)

LASER MATERIALS CHARACTERIZATION, MODELING, AND GROWTH

- 645118 **Laser performance of Yb³⁺:YAG ceramic microchip lasers [6451-41]**
J. Dong, A. Shirakawa, K. Ueda, Univ. of Electro-Communications (Japan); H. Yagi, T. Yanagitani, Konoshima Chemical Co., Ltd. (Japan); A. A. Kaminskii, Institute of Crystallography (Russia)

- 64511A **Modeling visible and infrared stimulated emission from Tb³⁺ in TbAlO₃** [6451-43]
K. L. Nash, J. B. Gruber, R. M. Yow, Univ. of Texas at San Antonio (USA); U. V. Valiev, National Univ. of Uzbekistan (Uzbekistan); D. K. Sardar, Univ. of Texas at San Antonio (USA)
- 64511B **Continuous-wave diode-pumped Yb:LuVO₄ lasers** [6451-44]
J. Liu, V. Petrov, X. Mateos, Max-Born-Institute for Nonlinear Optics and Ultrafast Spectroscopy (Germany); H. Zhang, J. Wang, M. Jiang, Shandong Univ. (China); S. Miller, G. Xu, U. Griebner, F. Noack, Max-Born-Institute for Nonlinear Optics and Ultrafast Spectroscopy (Germany)
- 64511C **Determination of Cr:LiSAF crystals ablation thresholds on the 20 ps regime using a diagonal scan** [6451-45]
R. E. Samad, S. L. Baldochi, N. D. Vieira, Jr., IPEN, Comissão Nacional de Energia Nuclear (Brazil)
- 64511D **Time-resolved pump-probe measurements of UV material cerium-doped BYF** [6451-46]
H. Liu, D. J. Spence, D. W. Coutts, Macquarie Univ. (Australia); M. Tonelli, A. Toncelli, NEST-CNR, Univ. di Pisa (Italy)

LASER SYSTEMS DESIGNS, MEASUREMENTS, AND MODELING

- 64511E **Detailed single-shot spectral diagnostics of Q-switched solid state lasers (Best Student Award Paper)** [6451-19]
C. Veltkamp, A. B. Petersen, J. D. Kafka, Spectra-Physics (USA)
- 64511F **High-power DPSS laser hosted on a HMW-THS** [6451-47]
M. Checchetti, MicrOptronics Srl (Italy)
- 64511H **1.44-μm giant pulse generation (Best Student Award Paper)** [6451-49]
J. Šulc, P. Arátor, H. Jelínková, Czech Technical Univ. Prague (Czech Republic); K. Nejezchleb, V. Škoda, Crytur, Ltd. (Czech Republic)

APPLICATIONS OF SOLID STATE LASERS

- 64511J **Industrial micromachining with advanced solid state lasers** [6451-52]
J. Stollhof, S. Weiler, C. Tan, I. Zawischa, D. H. Sutter, J. Kleinbauer, M. Kumkar, Trumpf Laser GmbH & Co. KG (Germany)
- 64511K **Advances in laser processing of microelectronics** [6451-53]
B. W. Baird, R. F. Hainsey, X. Peng, P. Y. Pirogovsky, Electro Scientific Industries, Inc. (USA)
- 64511L **Frequency stabilization of Q-switched Nd:YAG oscillators for airborne and spaceborne lidar systems** [6451-54]
K. Nicklaus, V. Morasch, M. Hofer, J. Luttmann, M. Vierkötter, Fraunhofer Institute for Laser Technology (Germany); M. Ostermeyer, Univ. of Potsdam (Germany); J. Höffner, Univ. Rostock (Germany); C. Lemmerz, Deutsches Zentrum für Luft- und Raumfahrt (Germany); D. Hoffmann, Fraunhofer Institute for Laser Technology (Germany)
- 64511M **The injection laser system on the National Ignition Facility** [6451-55]
M. Bowers, S. Burkhart, S. Cohen, G. Erbert, J. Heebner, M. Hermann, D. Jedlovec, Lawrence Livermore National Lab. (USA)

FIELD, AIR, AND SPACE QUALIFYABLE LASERS AND COMPONENTS

- 64511N **Narrow linewidth coherent beam combining of optical fiber amplifier arrays (Invited Paper)** [6451-57]
T. M. Shay, Air Force Research Lab. (USA); V. Benham, IIT Industries (USA); J. T. Baker, Boeing LTS Inc. (USA); A. D. Sanchez, D. Pilkington, D. J. Nelson, C. A. Lu, Air Force Research Lab. (USA)
- 64511Q **A consideration of the requirements for laser devices used in countermeasure applications (Invited Paper)** [6451-56]
D. H. Titterton, Defence Science and Technology Lab. (United Kingdom)
- 64511R **Thermal vacuum testing of the lunar orbiter laser altimeter engineering model laser** [6451-78]
A. W. Yu, A. M. Novo-Gradac, G. B. Shaw, J. Cavanaugh, NASA Goddard Space Flight Ctr. (USA); J. Guzek, Design Interface Inc. (USA); P. Liiva, Sigma Space Corp. (USA); L. Nagao, Orbital Sciences Corp. (USA); A. Rosanova, SSAI (USA)
- 64511S **Design considerations of the LOLA laser transmitter** [6451-79]
A. W. Yu, A. M. Novo-Gradac, G. B. Shaw, S. X. Li, M. Stephen, D. Krebs, G. Unger, J. Karsh, NASA Goddard Space Flight Ctr. (USA); W. Mamakos, J. Guzek, Design Interface Inc. (USA); A. Lukemire, Space Power Electronics Inc. (USA)

POSTER SESSION

- 64511T **Five simultaneously Q-switch mode-locked passive laser modulators** [6451-62]
J. Chen, Chung-Hua Univ. (Taiwan)
- 64511U **Ultra-narrow-linewidth combined CW Ti:sapphire/dye laser for atom cooling and high-precision spectroscopy** [6451-64]
S. Kobtsev, Novosibirsk State Univ. (Russia) and Tekhnoscan Joint-Stock Co. (Russia); V. Baraoulya, V. Lunin, Tekhnoscan Joint-Stock Co. (Russia)
- 64511V **A compact remote-controlled underwater lidar system** [6451-65]
Y. Zheng, K. Yang, J. Rao, M. Xia, Huazhong Univ. of Science and Technology (China)
- 645120 **Super-Gaussian pumping profiles for solid state lasers** [6451-50]
X. Liu, Y. Zhao, Beijing Institute of Technology (China); A. Yang, W. Xie, Western Photonics Technology (USA)

Author Index

Conference Committee

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Peter G. Schunemann, BAE Systems (USA)
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David H. Titterton, Defence Science and Technology Laboratory (United Kingdom)

Session Chairs

- 1 **UV Lasers: CW**
Norman Hodgson, Coherent, Inc. (USA)

- 2 UV Lasers: Pulsed
Norman Hodgson, Coherent, Inc. (USA)
- 3 Optically Pumped Semiconductors (OPS) and Disk Lasers
Alan B. Petersen, Spectra-Physics (USA)
- 4 New Developments in Diode Pumped Solid State Lasers
Hanna J. Hoffman, Liekki, Inc. (USA)
- 5 Mid IR Lasers
Ramesh K. Shori, Naval Air Warfare Center (USA)
- 6 Lasers in the Eye-Safe Range
Narasimha S. Prasad, NASA Langley Research Center (USA)
- 7 Injection Seeded and Frequency Stable Lasers
Iain T. McKinnie, Lockheed Martin Coherent Technologies (USA)
- 8 Cryogenically Cooled Lasers
Hans-Dieter Hoffman, Fraunhofer-Institut für Lasertechnik (Germany)
- 9 Tunable, Mode-Locked, and Ultrafast Lasers
William M. Grossman, JDS Uniphase Corporation (USA)
- 10 High Power Solid State Lasers Joint Session with Conference 6454
Steven J. Davis, Physical Sciences, Inc.
Hanna J. Hoffman, Liekki, Inc. (USA)
- 11 Laser Materials Characterization, Modeling, and Growth
Helena Jelínková, Czech Technical University in Prague (Czech Republic)
- 12 Laser Systems Designs, Measurements, and Modeling
David H. Titterton, Defence Science and Technology Laboratory (United Kingdom))
- 13 Applications of Solid State Lasers
Wolf R. Seelert, Coherent Lübeck GmbH (Germany)
- 14 Field, Air, and Space Qualifyable Lasers and Components
Ramesh K. Shori, Naval Air Warfare Center (USA)
Narasimha S. Prasad, NASA Langley Research Center (USA)